







2N4220/A, 2N4221/A N-Channel JFET

Features

- InterFET <u>N0016H Geometry</u>
- Typical Noise: 6 nV/vHz
- Low Ciss: 3.5pF Typical
- · High Input Impedance
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

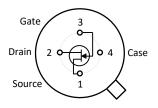
Applications

- Mixers
- Oscillators
- · Small Signal Amplifier
- VHF Amplifiers

Description

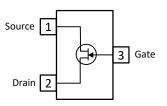
The -50V InterFET 2N4220/A and 2N4221/A are targeted for sensitive amplifier stages for midfrequencies designs. Gate leakages are typically less than 10pA at room temperatures. The "A" variants are screened for lower noise. The TO-72 package is hermetically sealed and suitable for military applications.

TO-72 Bottom View



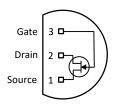


SOT23 Top View





TO-92 Bottom View





Product Summary

Parameters		2N4220/A Min	2N4221/A Min	Unit
BV _{GSS}	Gate to Source Breakdown Voltage	-30	-30	V
I _{DSS}	Drain to Source Saturation Current	0.5	2	mA
V _{GS(off)}	Gate to Source Cutoff Voltage			V
G _{FS}	Forward Transconductance	1000	2000	μS

Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
2N4220; 2N4221			
2N4220A; 2N4221A	Through-Hole	TO-72	Bulk
PN4220; PN4221			
PN4220A; PN4221A	Through-Hole	TO-92	Bulk
SMP4220; SMP4221			
SMP4220A; SMP4221A	Surface Mount	SOT23	Bulk
SMP4220TR; SMP4221TR	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMP4220ATR; SMP4221ATR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
2N4220COT; 2N4221COT	Chip Orientated Tray		
2N4220ACOT; 2N4221ACOT	(COT Waffle Pack)	СОТ	400/Waffle Pack
2N4220CFT; 2N4221CFT	Chip Face-up Tray		
2N4220ACFT; 2N4221ACFT	(CFT Waffle Pack)	CFT	400/Waffle Pack



Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.









Electrical Characteristics

Maximum Ratings (@ T_A = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
V_{RGS}	Reverse Gate Source and Gate Drain Voltage	-30	V
I _{FG}	Continuous Forward Gate Current	10	mA
PD	Continuous Device Power Dissipation	300	mW
Р	Power Derating	2	mW/°C
Tı	Operating Junction Temperature	-55 to 150	°C
T_{STG}	Storage Temperature	-65 to 175	°C

Static Characteristics (@ TA = 25°C, Unless otherwise specified, Highlighted values = A variant)

			2N4220/A		2N4221/A		
	Parameters	Conditions	Min	Max	Min	Max	Unit
V _{(BR)GSS}	Gate to Source Breakdown Voltage	$V_{DS} = 0V$, $I_G = -1\mu A$	-30		-30		V
	Gate to Source	$V_{GS} = -15V$, $V_{DS} = 0V$, $T_A = 25$ °C		-0.1		-0.1	nA
I _{GSS}	Reverse Current	$V_{GS} = -15V$, $V_{DS} = 0V$, $T_A = 150$ °C		-0.1		-0.1	μΑ
V _{GS}	Gate to Source	V _{DS} = 15V, I _D = ()	-0.5	-2.5	-1	-5	V
VGS	Voltage	VDS = 15V, ID = ()	(50)	(50)	(200)	(200)	μΑ
V _{GS(OFF)}	Gate to Source Cutoff Voltage	V _{DS} = 15V, I _D = 0.1nA		-4		-6	V
I _{DSS}	Drain to Source	$V_{GS} = 0V, V_{DS} = 15V$	0.5	3	2	6	mA
מטי	Saturation Current	(Pulsed)	0.5				ША

Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified, Highlighted values = A variant)

			2N4220/A		2N4221/A		
	Parameters	Conditions	Min	Max	Min	Max	Unit
G _{FS}	Forward Transconductance	V _{DS} = 15V, V _{GS} = 0V, f = 1kHz	1000	4000	2000	5000	μS
Gos	Output Conductance	V _{DS} = 15V, V _{GS} = 0V, f = 1kHz		10		20	μS
Y _{fs}	Forward Transmittance	V _{DS} = 15V, V _{GS} = 0V, f = 100MHz	750		750		μS
Ciss	Input Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1MHz		6		6	pF
C _{rss}	Reverse Transfer Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1MHz		2		2	pF
NF	Noise Figure	V_{DS} = 15V, V_{GS} = 0V, f = 100Hz R_G = 1 M Ω		2.5		2.5	dB



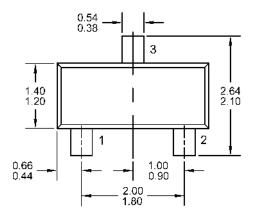


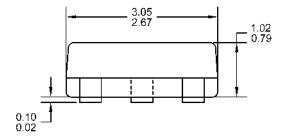


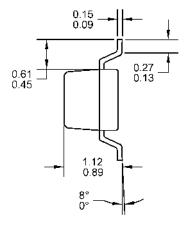


SOT23 (TO-236AB) Mechanical and Layout Data

Package Outline Data

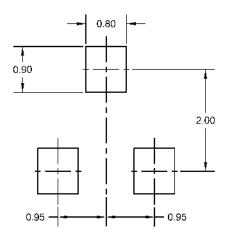






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

Suggested Pad Layout



- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.



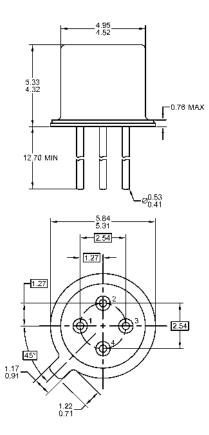






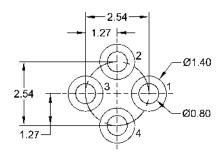
TO-72 Mechanical and Layout Data

Package Outline Data



- 1. All linear dimensions are in millimeters.
- Four leaded device. Not all leads are shown in drawing views.
- 3. Package weight approximately 0.31 grams
- Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.



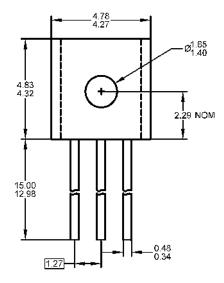


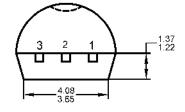


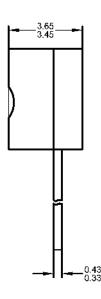


TO-92 Mechanical and Layout Data

Package Outline Data

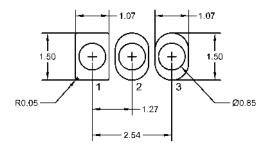






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.